

### SMT-AIDED COMBINATORIAL MATERIALS DISCOVERY



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#### Cornell Fuel Cell Institute

Mission: develop **new materials** for **fuel cells**.

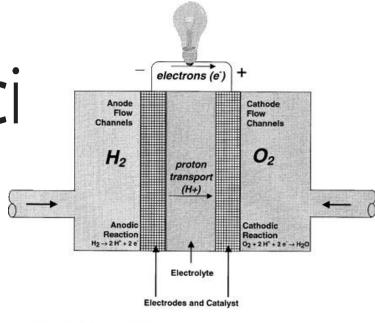


Figure 1. Fuel cell schematic.

Source: Annual Reveiws of Energy and the Environment. http://energy.annualreviews.org/cgi/content/full/24/1/281

#### An **Electrocatalyst** must:

- Be electronically conducting
- 2) Facilitate both reactions

**Platinum** is the best known metal to fulfill that role, but:

- The reaction rate is still considered slow (causing energy loss)
- Platinum is fairly costly, intolerant to fuel contaminants, and has a short lifetime.

Goal: Find an intermetallic compound that is a better catalyst than Pt.

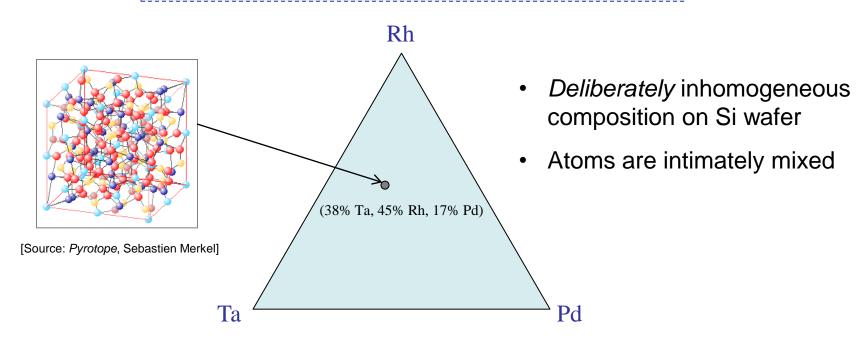






#### Recipe for finding alternatives to Platinum

- 1) In a vacuum chamber, place a silicon wafer.
- 2) Add three metals.
- 3) Mix until smooth, using three sputter guns.
- 4) Bake for 2 hours at 650°C



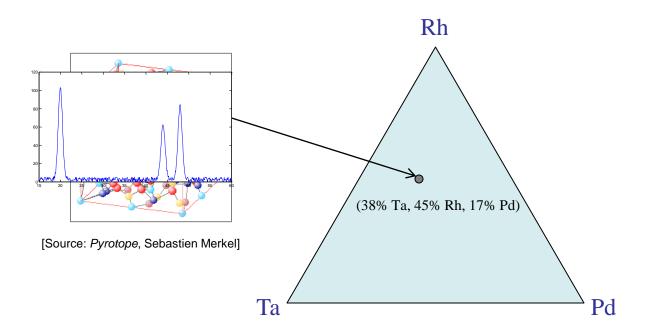


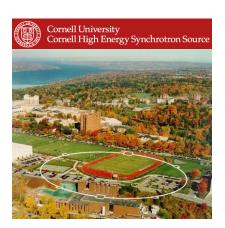




Identifying crystal structure using X-Ray Diffraction at CHESS

- XRD pattern characterizes the underlying crystal fairly well
- Expensive experimentations: Bruce van Dover's research team has access to the facility one week every year.

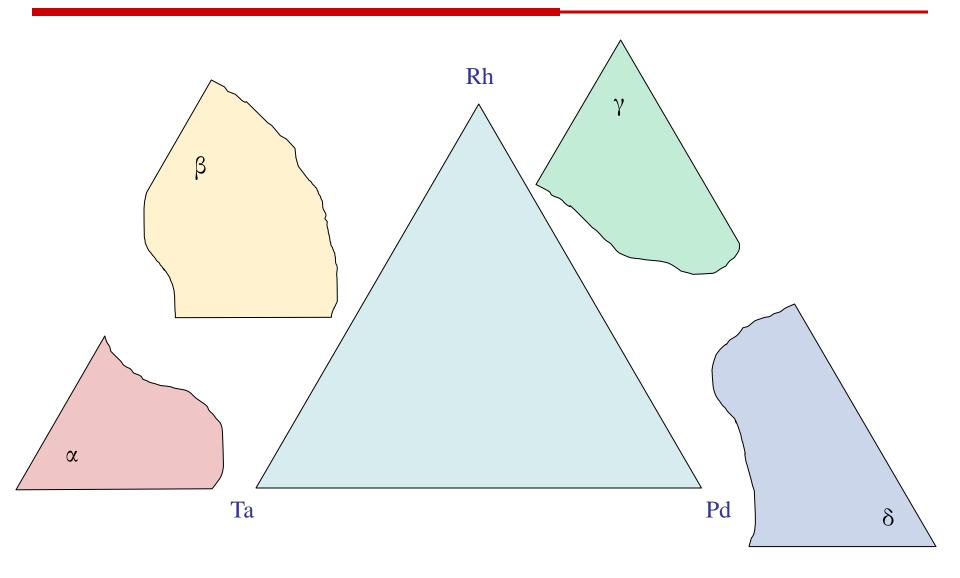








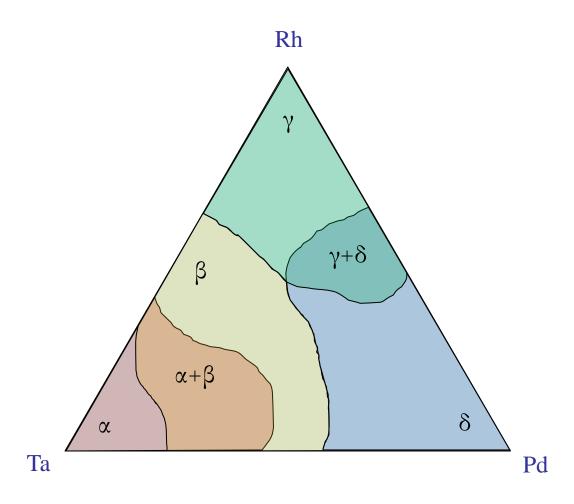








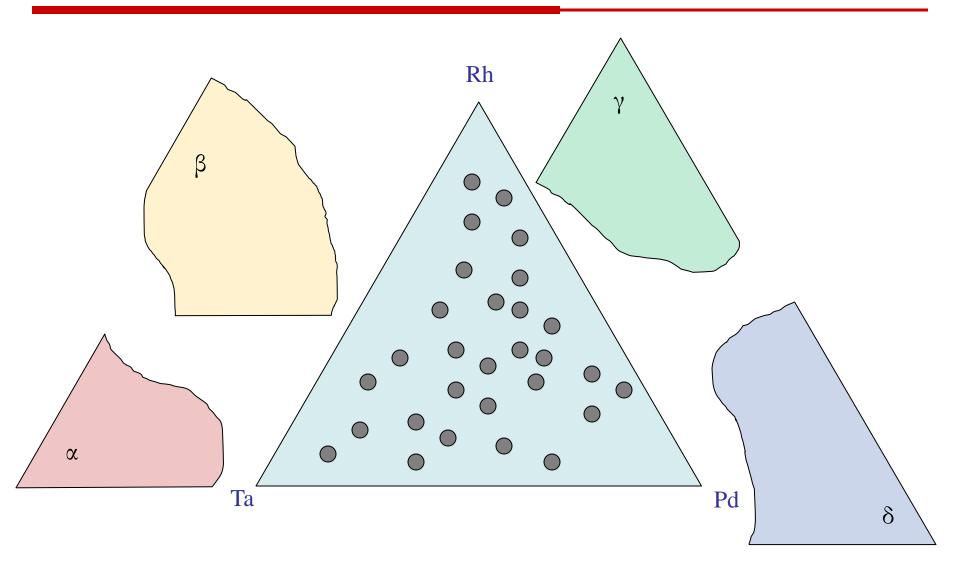








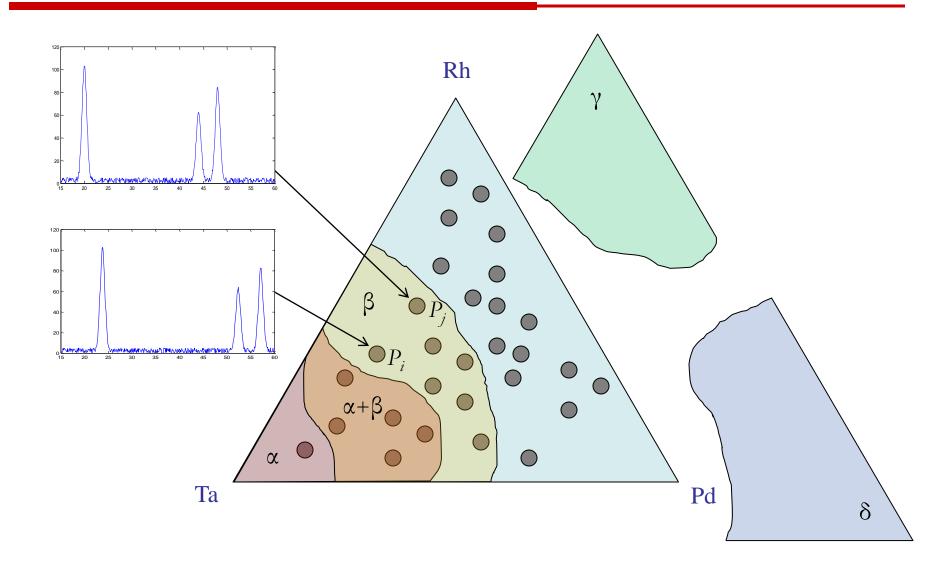








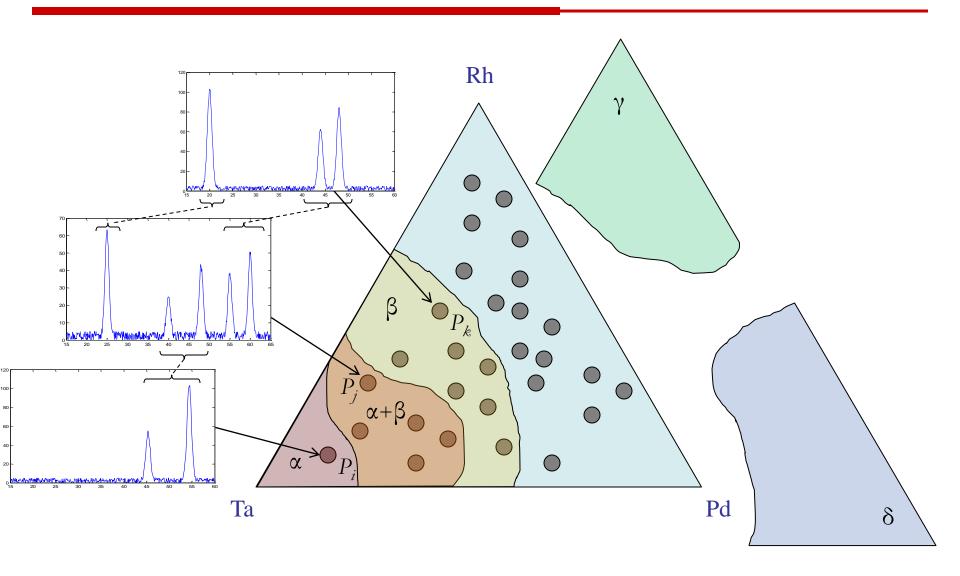








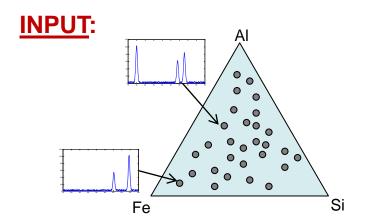


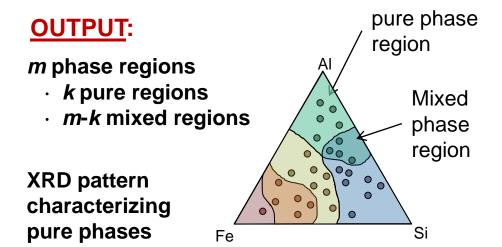












#### **Additional Physical characteristics:**

- Phase Connectivity
- Mixtures of ≤ 3 pure phases
- Peaks shift by ≤ 15% within a region
  - Continuous and Monotonic
- Noisy detection







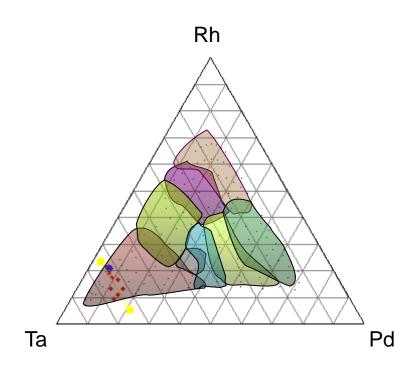


Figure 1: Phase regions of Ta-Rh-Pd

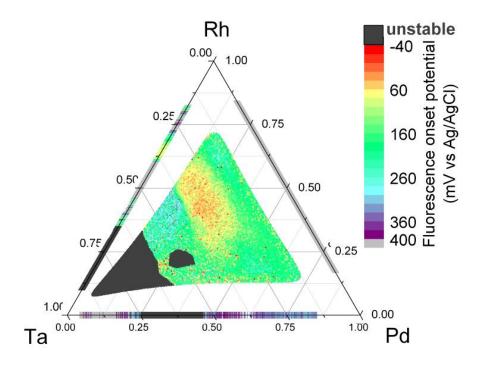


Figure 2: Fluorescence activity of Ta-Rh-Pd



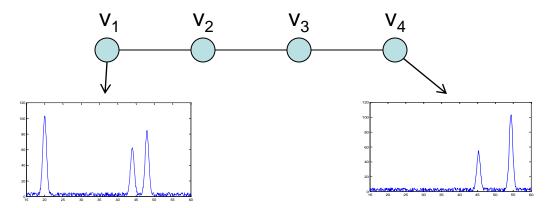
### **Problem Definition**



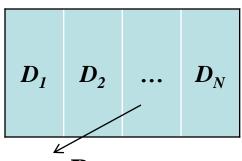


#### • Input:

• A graph G representing the points on the silicon wafer



- A real vector  $\mathbf{D}_i$  per vertex  $v_i$  (diffraction patterns)
- *K* = user specified number of pure phases
- Goal: a basis of K vectors for





$$\boldsymbol{D}_i = a_{il}\boldsymbol{B}_1 + \dots + a_{iK}\boldsymbol{B}_K$$

#### Problem Definition





• There is experimental noise

$$\boldsymbol{D}_i = a_{il}\boldsymbol{B}_1 + \dots + a_{iK}\boldsymbol{B}_K$$



$$min || \mathbf{D}_i - a_{il} \mathbf{B}_l + \dots + a_{ik} \mathbf{B}_k ||$$

Minimize norm instead

Non-negative basis vectors and coefficients

$$\boldsymbol{B_i} \ge \boldsymbol{0}$$
 ,  $a_{ij} \ge 0$ 

At most M (=3) non-zero coefficients per point

$$|\{j\mid a_{ij}>0\}|\leq M$$

• Basis patterns appear in **contiguous** locations on silicon wafer The subgraph induced by  $|\{i \mid a_{ij} > 0\}|$  is connected

#### Problem Definition





Basis vector can be shifted

Shift Shift operator coefficients 
$$\| \boldsymbol{D_i} - a_{il} \boldsymbol{S}(\boldsymbol{B_{I,S_{il}}}) + \dots + a_{iK} \boldsymbol{S}(\boldsymbol{B_{K,S_{iK}}}) \|$$

Shifts coefficients are bounded, continuous and monotonic

$$|S_{11}| \leq |S_{12}| \leq |S_{13}| \leq |S_{14}|$$

$$|S_{12} - S_{11}| \leq c$$

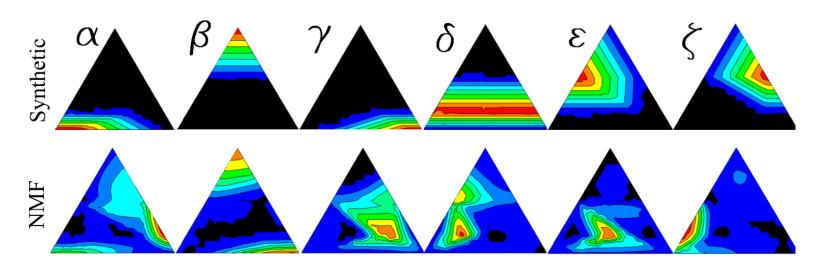
It is a form of constrained Principal Component Analysis (Singular Value Decomposition)

### Prior Work/Machine Learning





- Ignore most of the constraints, and shifting
  - Non-negative matrix factorization
  - Good scaling
  - Cannot enforce the combinatorial constraints (e.g., connectivity)



[Source:Le Bras et al., 2011]



#### Prior Work / CP





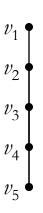
- Constraint Programming formulation [Le Bras et al., CP 2011]
   Pattern Decomposition with Scaling:
  - Imitate what humans do. Instead of considering full spectra, focus on the peaks.
  - Encoding based on set-variables
  - Does not scale to realistic sized problems
  - Useful in combination with clustering-based heuristic







- Arithmetic based approach (SMT):
  - Initial graph G representing points on the wafer

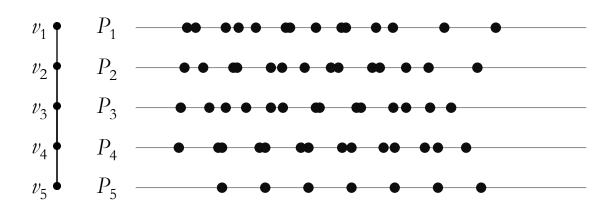








- Arithmetic based approach (SMT):
  - Initial graph G representing points on the wafer
  - Peak detection to extract a set of peaks P<sub>i</sub> for each diffraction pattern D<sub>i</sub>

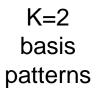


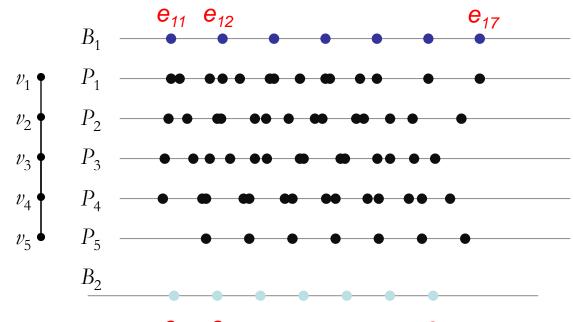






- Arithmetic based approach (SMT):
  - Initial graph G
  - Peak detection to extract a set of peaks  $P_i$  for each diffraction pattern  $D_i$
  - Real variables  $e_{ij}$  for the **peak locations** in each  $B_i$



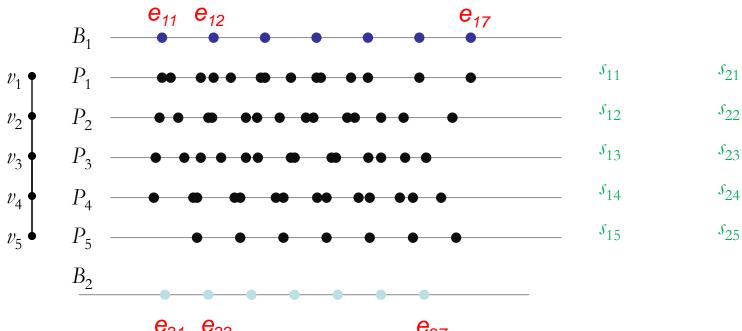








- Arithmetic based approach (SMT):
  - Real variables  $e_{ij}$  for the **peak locations** in each  $B_i$
  - Real variables for the shift coefficients s<sub>ij</sub>



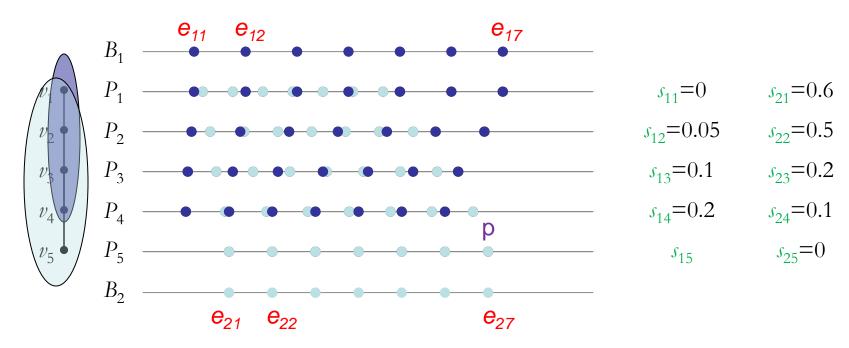






#### Arithmetic based approach (SMT):

- Real variables  $e_{ii}$  for the **peak locations** in each  $B_i$
- Real variables for the shift coefficients s<sub>ij</sub>
- An observed peak p is "explained" if there exists  $s_{ij}$ ,  $e_{il}$  s.t.  $|p-(s_{ii}+e_{il})| \le \varepsilon$

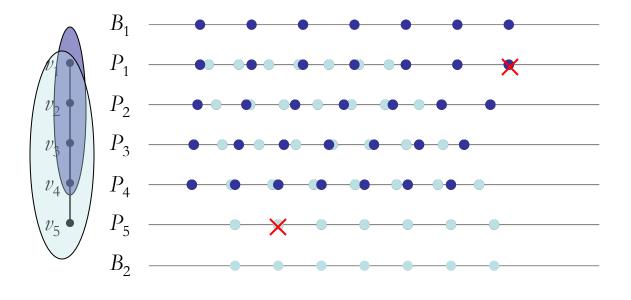






#### •Arithmetic based approach (SMT):

- Every observed peak must be "explained"
- Bound the number of missing peaks  $\leq T$
- Minimization by (binary) search on T



$$s_{11}=0$$
  $s_{21}=0.6$ 

$$s_{12} = 0.05$$
  $s_{22} = 0.5$ 

$$s_{13} = 0.1$$
  $s_{23} = 0.2$ 

$$s_{14} = 0.2$$
  $s_{24} = 0.1$ 

$$s_{15}$$
  $s_{25}=0$ 



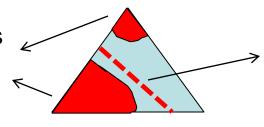
## SMT formulation (continued)





- Arithmetic-based SMT encoding:
  - Linear phase usage constraint (up to M basis patterns per point)
  - Linear constraint for shift monotonicity and continuity ( $s_{ij} \le s_{lm}$ )
  - Lazy connectivity: add a cut if current solution is not connected

If disconnected regions explained with phase 1



Then Phase 1
must appear in at
least one of
these points

- Symmetry breaking:
  - Renaming of pure phases
  - Order of the peaks location  $e_{ii}$  (per basis pattern)



#### **Quantifier-free linear arithmetic**

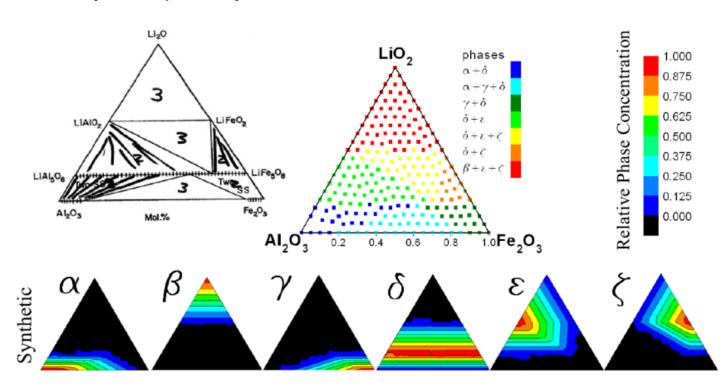


# **Experimental Results**





- Use synthetic instances from the Al-Li-Fe ternary system
  - Known ground truth
  - Fairly complex system





### Runtime





# Points	Unknown Phases	Arithmetic + Z3 (s)	Set-based + CPLEX (s)
10	3	8	0.5
	6	12	Timeout
15	3	13	0.5
	6	20	Timeout
18	3	29	384.8
	6	125	Timeout
29	3	78	276
	6	186	Timeout
45	6	518	Timeout

Z3 scales to realistic sized problems!

Arithmetic encoding translated to CP and MIP:

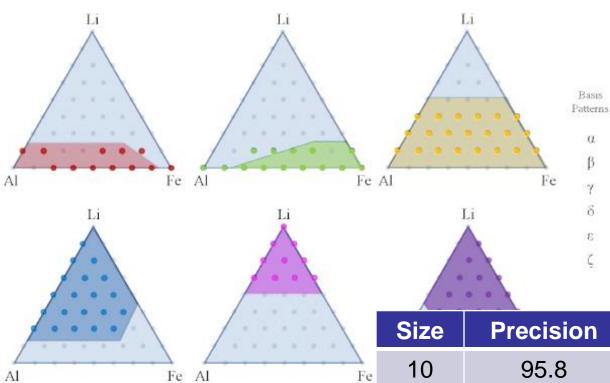
- MIP is appealing because it can optimize the objective
- They don't scale → SMT solving strategy



### Precision/Recall







Recovers ground truth

Size	Precision	Recall
10	95.8	100
15	96.6	100
18	97.2	96.6
29	96.1	92.8
45	95.8	91.6

Ground SMT

Truth Results



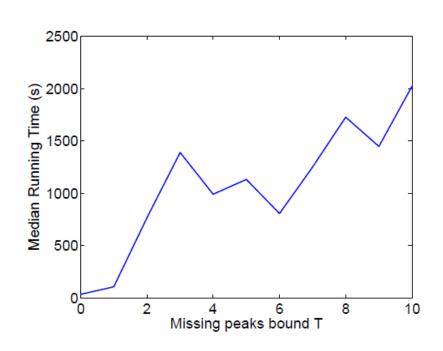
### Robustness





- Remove some peaks to simulate experimental noise
- Size = 15 points

Missing Peaks	Precision	Recall
1	96.1	99.6
2	96.3	99.3
3	96.7	99.5
4	95.3	98.9
5	94.8	99.7



Solutions are still accurate. Runtime increases approx linearly.



### Conclusion





- New arithmetic-based encoding for Materials Discovery
- Good performance on synthetic data:
  - Scales to realistic sized problems (~50 points)
  - SMT outperforms previous one based on setvariables
  - Good accuracy (>90% precision and recall)
  - (likely) due to SMT solving procedure
- Exciting results analyzing and explaining real-world data





# THANK YOU!



# Extra slides



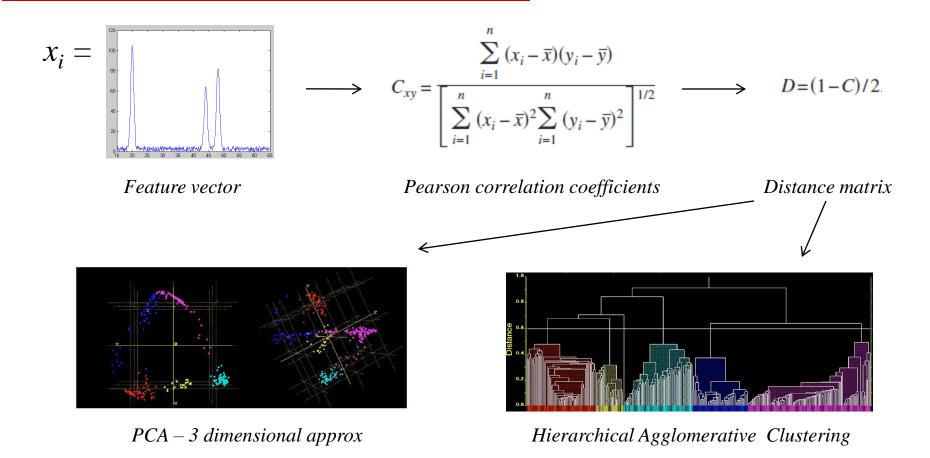




### Previous Work 1: Cluster Analysis [Long et al., 2007]







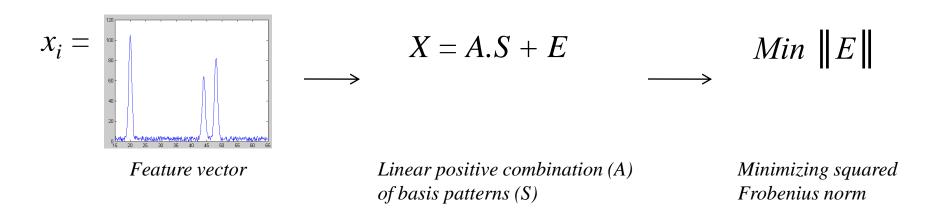
**Drawback:** Requires sampling of pure phases, detects phase regions (not phases), overlooks peak shifts, may violate physical constraints (phase continuity, etc.).



### Previous Work 2: NMF [Long et al., 2009]







**Drawback:** Overlooks peak shifts (linear combination only), may violate physical constraints (phase continuity, etc.).



### **SMT** formulation





#### Parameters

- Number of pure phases K, tolerance ε
- Key components
  - Variables peak positions per base
  - Shifts per point
  - Point p is explained by base k



### SMT formulation





- New arithmetic-based encoding:
  - Real variables  $e_{ii}$  for the peak locations in each  $B_i$
  - Real variables for the shift coefficients  $s_{ij}$  (per base, per point)
  - An observed peak p is explained if  $|p-s_{ij}-e_{ij}| \le \varepsilon$  (Match the height of the peaks)
  - Bound the number of missing peaks ≤ *T*

